

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7W66FU, TC7W66FK

Dual Bilateral Switch

The TC7W66 is a high speed CMOS Dual Bilateral Switch fabricated with silicon gate CMOS technology.

It consists of four independent high speed switches capable of controlling either digital or analog signals while maintaining the CMOS low power dissipation.

Control input (C) is provided to control the switch.

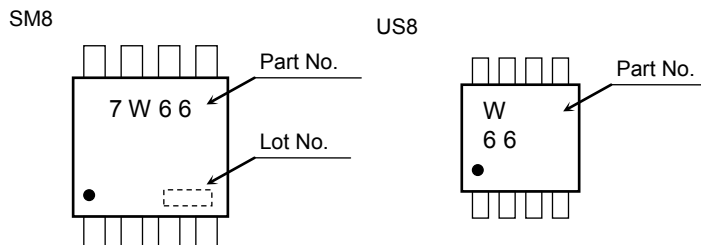
The switch turns ON while the C input is high, and the switch turns OFF while low.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

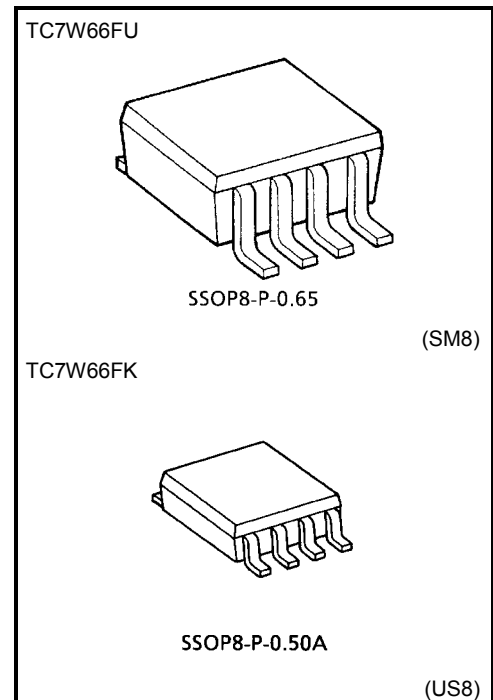
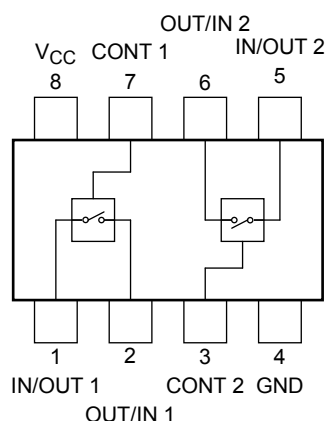
Features

- High speed: $t_{pd} = 7 \text{ ns}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 1 \mu\text{A}$ (max) at $T_a = 25^\circ\text{C}$
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (min)
- Low ON resistance: $R_{ON} = 50 \Omega$ (typ.) at $V_{CC} = 9 \text{ V}$
- High degree of linearity: $THD = 0.05\%$ (typ.) at $V_{CC} = 5 \text{ V}$
- Pin and function compatible with TC4W66

Marking



Pin Configuration (top view)



Weight

SSOP8-P-0.65: 0.02 g (typ.)
SSOP8-P-0.50A: 0.01 g (typ.)

Start of commercial production
1996-02

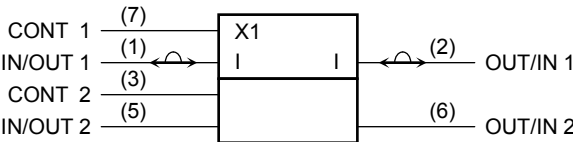
Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	−0.5 to 13	V
DC input voltage	V _{IN}	−0.5 to V _{CC} + 0.5	V
DC output voltage	V _{OUT}	−0.5 to V _{CC} + 0.5	V
Input diode current	I _{IK}	±20	mA
Output diode current	I _{OK}	±20	mA
DC output current	I _{OUT}	±25	mA
DC V _{CC} /ground current	I _{CC}	±25	mA
Power dissipation	P _D	300 (SM8)	mW
		200 (US8)	
Storage temperature range	T _{stg}	−65 to 150	°C
Lead temperature (10 s)	T _L	260	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

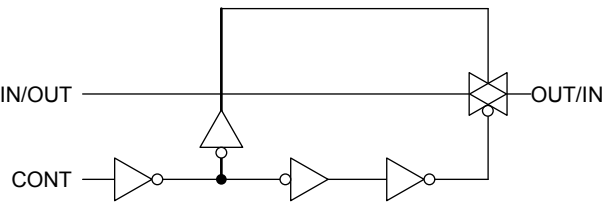
Logic Diagram



Truth Table

Control	Switch Function
H	ON
L	OFF

Logic Diagram (1/2 TC7W66)



Operating Ranges

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	2 to 12	V
Control input voltage	V_{IN}	0 to V_{CC}	V
Switch I/O voltage	$V_{I/O}$	0 to V_{CC}	V
Operating temperature range	T_{opr}	-40 to 85	°C
Input rise and fall time	t_r, t_f	0 to 1000 ($V_{CC} = 2.0$ V)	ns
		0 to 500 ($V_{CC} = 4.5$ V)	
		0 to 400 ($V_{CC} = 6.0$ V)	
		0 to 250 ($V_{CC} = 10.0$ V)	

Electrical Characteristics
DC Electrical Characteristics

Characteristics		Symbol	Test Condition	Ta = 25°C				Ta = -40 to 85°C		Unit
				VCC (V)	Min	Typ.	Max	Min	Max	
Control input voltage	High level	VIHC	—	2.0	1.5	—	—	1.5	—	V
				4.5	3.15	—	—	3.15	—	
				9.0	6.3	—	—	6.3	—	
				12.0	8.4	—	—	8.4	—	
	Low level	VILC	—	2.0	—	—	0.5	—	0.5	
				4.5	—	—	1.35	—	1.35	
				9.0	—	—	2.7	—	2.7	
				12.0	—	—	3.6	—	3.6	
ON resistance		RON	VIN = VIHC VIO = VCC to GND IIO ≤ 1 mA	4.5	—	96	170	—	200	Ω
				9.0	—	55	85	—	100	
				12.0	—	45	80	—	90	
			VIN = VIHC VIO = VCC or GND IIO ≤ 1 mA	2.0	—	160	—	—	—	
				4.5	—	70	100	—	130	
				9.0	—	50	75	—	95	
				12.0	—	45	70	—	90	
				Difference of ON resistance between switches	ΔRON	VIN = VIHC VIO = VCC to GND IIO ≤ 1 mA	4.5	—	10	
9.0	—	5	—				—	—		
12.0	—	5	—				—	—		
Input/output leakage current (switch off)		IOFF	VOS = VCC or GND VIS = GND or VCC VIN = VILC	12.0	—	—	±100	—	±1000	nA
Switch input leakage current (switch on output open)		IIZ	VOS = VCC or GND VIN = VIHC	12.0	—	—	±100	—	±1000	nA
Control input current		IIN	VIN = VCC or GND	12.0	—	—	±100	—	±1000	nA
Quiescent supply current		ICC	VIN = VCC or GND	6.0	—	—	1.0	—	10.0	μA
				9.0	—	—	4.0	—	40.0	
				12.0	—	—	8.0	—	80.0	

AC Electrical Characteristics ($C_L = 50$ pF, input $t_r = t_f = 6$ ns)

Characteristics	Symbol	Test Condition	Ta = 25°C			Ta = -40 to 85°C		Unit
			V _{CC} (V)	Min	Typ.	Max	Min	Max
Phase difference between input and output	$\phi_{I/O}$	—	2.0	—	10	50	—	65
			4.5	—	4	10	—	13
			9.0	—	3	8	—	10
			12.0	—	3	7	—	9
Output enable time	t_{pZL} t_{pZH}	$R_L = 1$ k Ω	2.0	—	18	100	—	125
			4.5	—	8	20	—	25
			9.0	—	6	12	—	22
			12.0	—	6	12	—	18
Output disable time	t_{pLZ} t_{pHZ}	$R_L = 1$ k Ω	2.0	—	20	115	—	145
			4.5	—	10	23	—	29
			9.0	—	8	20	—	25
			12.0	—	8	18	—	22
Maximum control input frequency	—	$R_L = 1$ k Ω $C_L = 15$ pF $V_{OUT} = 1/2 V_{CC}$	2.0	—	30	—	—	—
			4.5	—	30	—	—	—
			9.0	—	30	—	—	—
			12.0	—	30	—	—	—
Control input capacitance	C_{IN}	—	—	—	5	10	—	10
Switch terminal capacitance	$C_{I/O}$	—	—	—	6	—	—	—
Feed through capacitance	C_{IOS}	—	—	—	0.5	—	—	—
Power dissipation capacitance	C_{PD}	(Note)	—	—	15	—	—	—

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

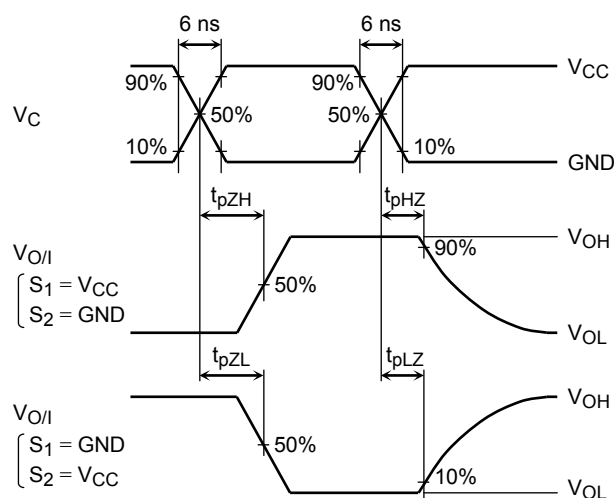
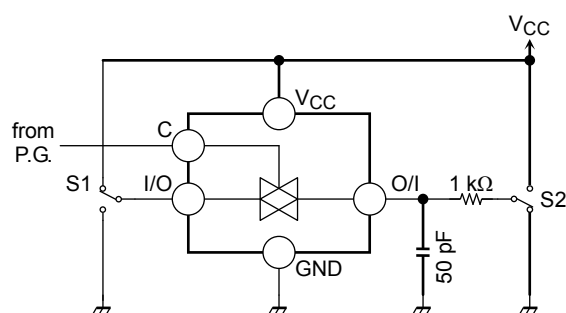
$$I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2$$

Analog Switch Characteristics (GND = 0 V, Ta = 25°C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Typ.	Unit
Sine wave distortion (T.H.D)	—	f _{IN} = 1 kHz, V _{IN} = 4.0 V _{p-p} @V _{CC} = 4.5 V R _L = 10 kΩ, V _{IN} = 8.0 V _{p-p} @V _{CC} = 9.0 V C _L = 50 pF	4.5	0.05	%
			9.0	0.04	
Frequency response (switch ON)	f _{MAX}	Adjust V _{IN} voltage to obtain 0dBm at V _{OS} Increase f _{IN} frequency until dB Meter reads -3dB R _L = 50 Ω, C _L = 10 pF f _{IN} = 1 MHz, sine wave	4.5	200	MHz
			9.0	200	
Feed Through attenuation (switch OFF)	—	V _{IN} is centered at V _{CC} /2 Adjust input for 0dBm R _L = 600 Ω, C _L = 50 pF f _{IN} = 1 MHz, sine wave	4.5	-60	dB
			9.0	-60	
Crosstalk (control input to signal output)	—	R _L = 600 Ω, C _L = 50 pF f _{IN} = 1 MHz, square wave (t _r = t _f = 6 ns)	4.5	60	mV
			9.0	100	
Crosstalk (between any switches)	—	Adjust V _{IN} to obtain 0dBm at input R _L = 600 Ω, C _L = 50 pF f _{IN} = 1 MHz, sine wave	4.5	-60	dB
			9.0	-60	

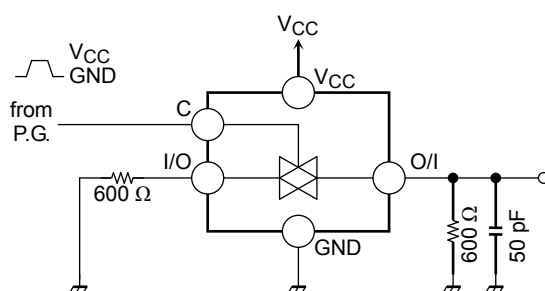
Switching Characteristics Test Circuits

1. t_{pLZ} , t_{pHZ} , t_{pZL} , t_{pZH}

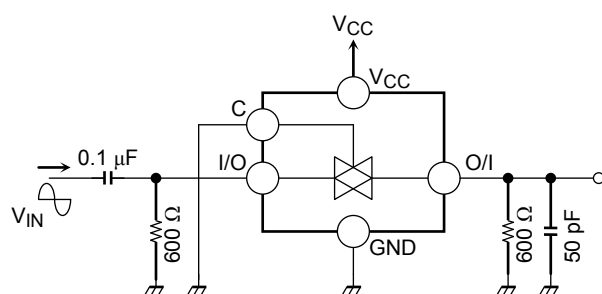


2. Cross Talk (control input-switch output)

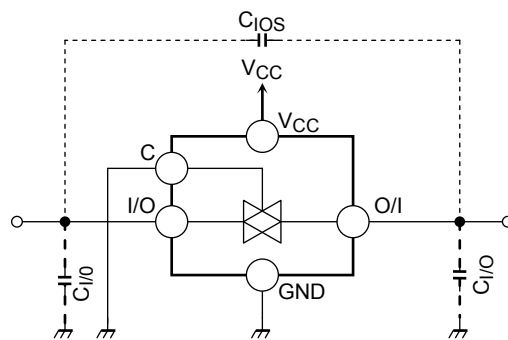
$f_{IN} = 1 \text{ MHz}$, duty = 50%, $t_r = t_f = 6 \text{ ns}$



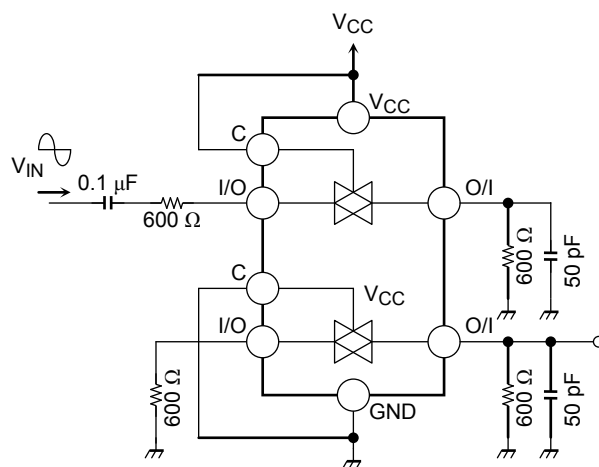
3. Feed Through Attenuation



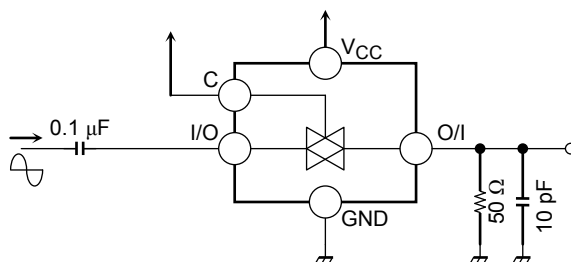
4. $C_{I/O}$, $C_{I/O}$



5. Cross Talk (between any two switches)



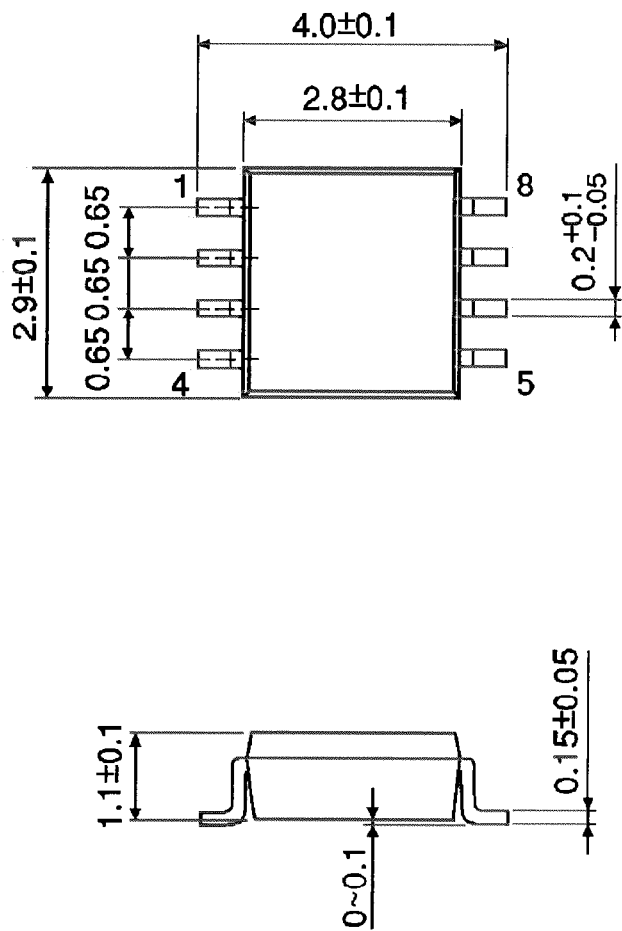
6. Frequency Response (switch ON)



Package Dimensions

SSOP8-P-0.65

Unit : mm

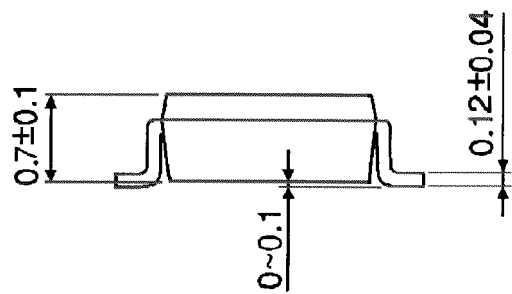
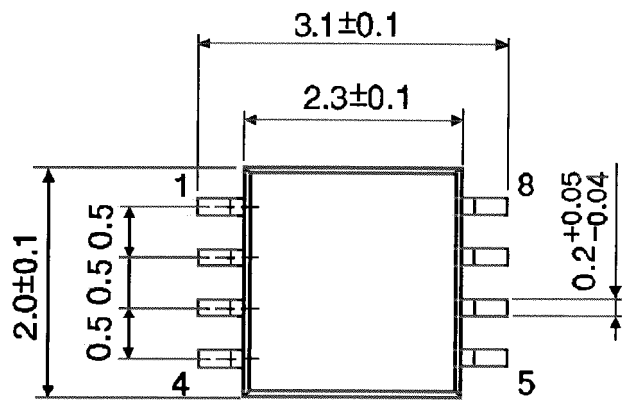


Weight: 0.02 g (typ.)

Package Dimensions

SSOP8-P-0.50A

Unit : mm



Weight: 0.01 g (typ.)

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